

VHF AMPLIFIER MODULE

A broadband VHF amplifier module primarily designed for use in portable transmitters operating from 9.6 V electrical battery supply.

The module is a two-stage RF amplifier consisting of n-channel FETs, with lumped-element matching and bias circuits.

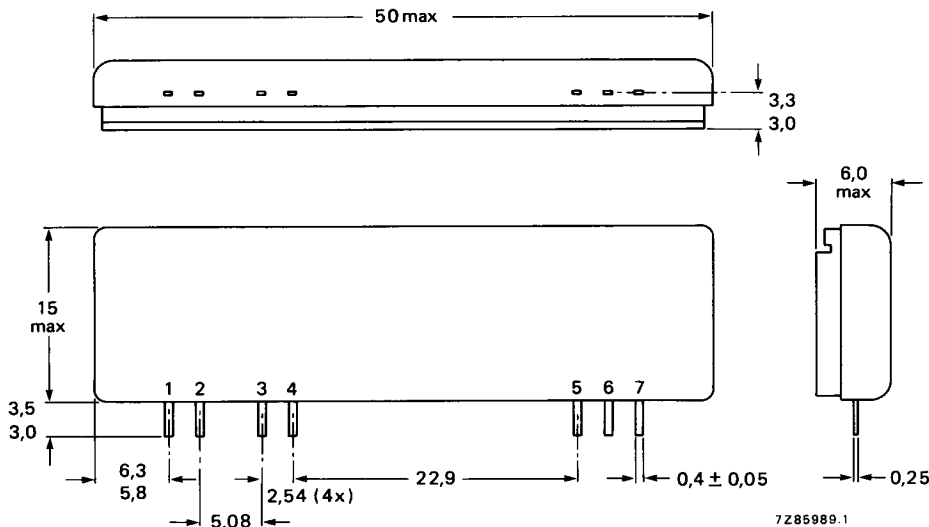
The module will produce a minimum of 5 W into a 50 Ω load over the frequency range of 148 to 174 MHz.

QUICK REFERENCE DATA

Mode of operation			CW
Frequency range			148 to 174 MHz
DC supply voltages	V_{S1}, V_{S2}	nom.	9.6 V
Drive power	P_D	max.	35 mW
Load power	P_L	>	5.0 W
Input, output impedance	z_i, z_L	nom.	50 Ω

MECHANICAL DATA

Dimensions in mm



Lead reference

- 1 = RF input
- 2 = Earth

- 3 = V_{S1} and second stage bias

- 4 = Earth

Fig. 1 SOT-182.

- 5 = V_{S2}

- 6 = Earth

- 7 = RF output

Flange = Earth

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

DC supply terminal voltages*	V_{S1}, V_{S2}	max.	13.5 V
RF input terminal voltage*	$\pm V_i$	max.	25 V
RF output terminal voltage*	$\pm V_o$	max.	25 V
Load power (see Fig. 2)	P_L	max.	9.0 W
Drive power	P_D	max.	70 mW
Storage temperature range	T_{stg}		-40 to + 100 °C
Operating heatsink temperature	T_h	max.	90 °C

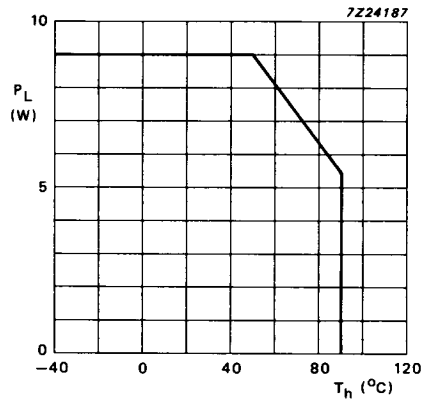


Fig. 2 Load power derating; VSWR = 1 : 1.

* With respect to earth.

CHARACTERISTICS

$T_h = 25\text{ }^\circ\text{C}$ unless otherwise stated

$V_{S1} = V_{S2} = 9.6\text{ V}$; $R_S = R_L = 50\ \Omega$; $f = 148$ to 174 MHz .

Quiescent currents

first stage current $P_D = 0$	I_{Q1}	typ.	125 mA
second stage current with first stage open circuit $P_D = 0$; $I_{S1} = 0$	I_{Q2}	<	0.5 mA
RF drive power $P_L = 5.0\text{ W}$	P_D	<	35 mW
Efficiency $P_L = 5.0\text{ W}$	η	> typ.	40 % 46 %
Harmonic output	any harmonic (relative to carrier)	<	-35 dB
Input VSWR with respect to $50\ \Omega$	VSWR	max.	2 : 1

Stability

The module is stable with load VSWR up to 8 (all phases) when operated within the following conditions:

$V_{S1} \leq V_{S2} = 4$ to 11.2 V ; $f = 148$ to 174 MHz ; $P_D = 17$ to 70 mW ; $P_L < 9\text{ W}$ (matched).

Ruggedness

The module will withstand a load VSWR of 50 for short period overload conditions, with P_D , V_{S1} and V_{S2} at maximum values, providing the combination does not result in the matched RF output power derating curve being exceeded ($T_h < 90\text{ }^\circ\text{C}$).

Mounting

To ensure good thermal transfer the module should be mounted onto a heatsink with a flat surface and heat-conducting compound applied between module and heatsink. The module is designed to be pressed against the heatsink by a sheet spring applying up to 50 N to the top surface of the module encapsulation. The leads of the devices may be soldered directly into a circuit using a soldering iron with a maximum temperature of 245 °C for not more than 10 s at a distance of at least 1 mm from the plastic.

Power rating

In general it is recommended that the output power from the module under nominal conditions should not exceed 7 W in order to provide an adequate safety margin under fault conditions.

Gain control

The module is designed to be operated at a constant output power of 5 W. The module is adjusted to produce nominal output power by reducing the first stage supply voltage (V_{S1}). If the module is to be used over a range of output power levels below 5 W the first stage supply voltage should not be reduced below 4 V. If further reductions in power are needed this may be achieved by varying the drive power (P_D), however for stable operation care must be taken to avoid operating the module outside the published stability conditions.

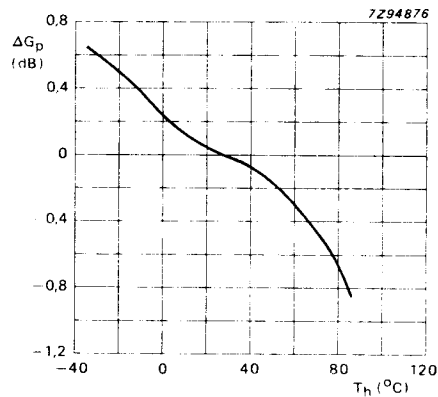


Fig. 3 Power gain as a function of temperature; $V_{S1} = V_{S2} = 9.6$ V; $P_D = 35$ mW; $f = 161$ MHz.

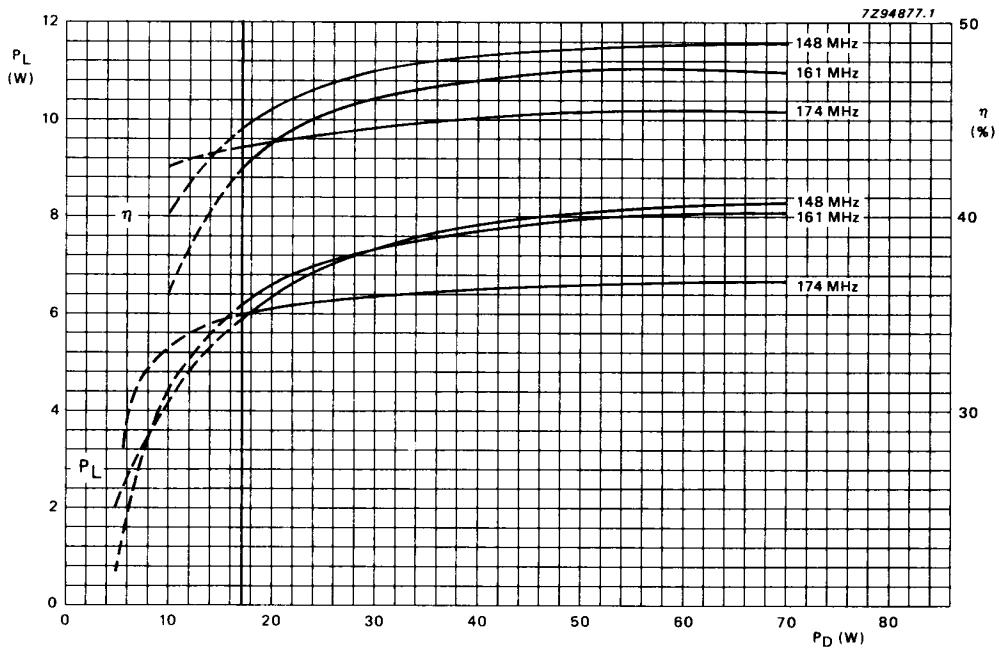


Fig. 4 Load power and efficiency as functions of drive power; $V_{S1} = V_{S2} = 9.6$ V; typical values.

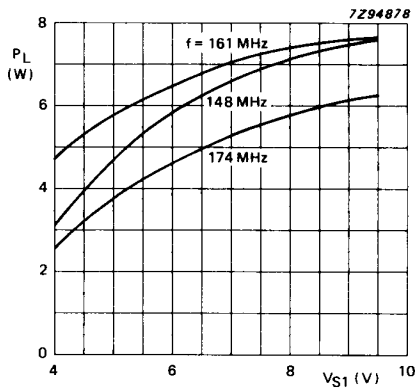


Fig. 5 Load power as a function of supply voltage V_{S1} ; $P_D = 35$ mW; $V_{S2} = 9.6$ V; typical values.

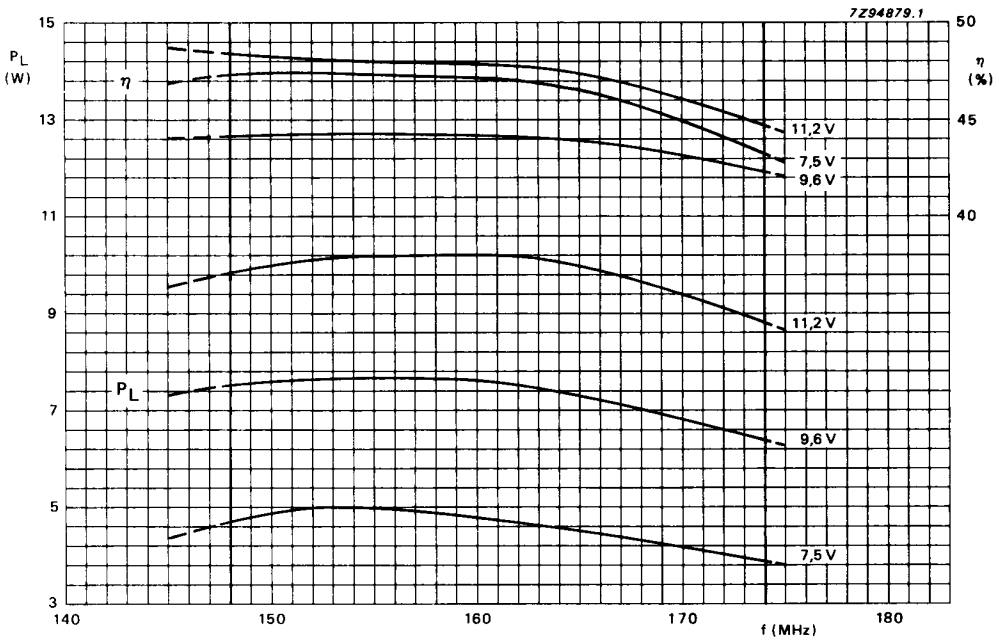


Fig. 6 Load power and efficiency as functions of frequency; $V_{S1} = V_{S2}$; $P_D = 35$ mW; typical values.

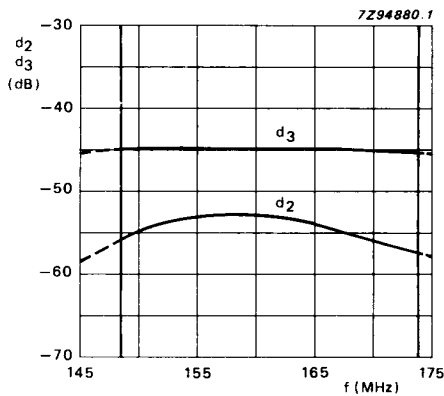


Fig. 7 Second and third harmonic distortion as a function of frequency; $V_{S1} = V_{S2} = 9.6$ V; $P_D = 35$ mW; typical values.